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# **H8SX Family**

Transfer between Synchronous DRAM and External SRAM with EXDMAC (Extended Repeat Area Function)

#### Introduction

The extended repeat area function of the EXDMAC in normal transfer mode is used to transfer data from the synchronous DRAM area (hereafter referred to as SDRAM) to the SRAM area.

The EXDMAC can be used to transfer data between external memories, reducing the load on the CPU.

Furthermore, with the extended repeat area function, values of the higher-order bits in the transfer address register are fixed, and values of the lower-order bits are incremented or decremented so that data can be transferred for repeated address values in a specified range.

# **Target Device**

H8SX/1668R

#### **Preface**

The writing of this application note is in accord with the hardware manual for the H8SX/1668R Group, and the program covered herein can be run on the target device indicated above. However, since some functional modules may be changed for the addition of functionality, etc., be sure to perform a thorough evaluation by confirming the details with the hardware manual for the target device.

#### **Contents**

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# 1. Specifications

An overview of operation in this application note is given in figure 1, and connections between the external memory and the CPU are shown in figure 2.

The operation in this application note is explained as follows:

- EXDMAC is activated on the falling edge of the EDREQ pin.
- TPU compare match output is used as the input to the  $\overline{\text{EDREQ}}$  pin.
- The transfer source is specified as extended repeat area function (the three lower-order bits (8-byte area) of transfer source address are designated as extended repeat area).
- EXDMAC transfers 256-byte data from the SDRAM area to the SRAM area.
- SDRAM and SRAM use area 2 and area 4, respectively.
- After an EXDMAC transfer, the source and destination data are compared, and the result of the comparison is output to an I/O port.

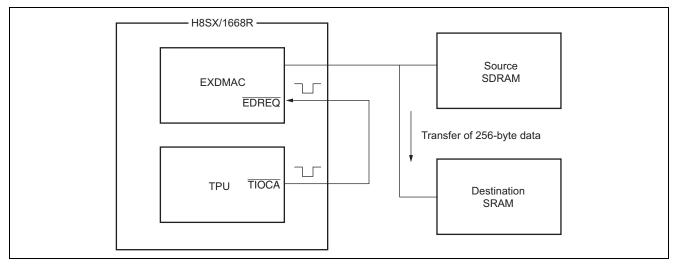


Figure 1 Overview of Operation

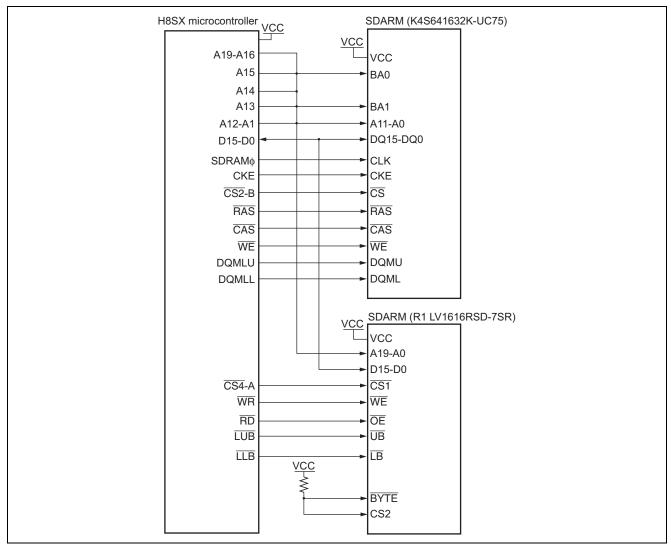


Figure 2 **Connections between External Memory and CPU** 

EXDMAC transfer settings are listed in table 1.

In addition, comparison of data transferred is listed in table 2.

### Table 1 EXDMAC Transfer Settings

Item	Setting
EXDMAC transfer request	External request mode
Bus mode	Cycle stealing mode
Transfer mode	Normal transfer mode
Address mode	Dual address mode
Transfer size	Byte
Source/destination address update	Incremented according to the data access size
Extended repeat area	Source addresses

Table 2 Comparison of Data Transferred

Comparison Result	Output Value (using port 3)
Matched	H'55
Unmatched	H'FF



# 2. Applicable Conditions

### **Table 3 Applicable Conditions**

Item	Detail			
Operation frequency	Input clock	: 12.5 MHz		
	System clock (Iφ)	: 50 MHz (12.5 MHz multiplied by 4)		
	Peripheral module clock (Pφ)	: 25 MHz (12.5 MHz multiplied by 2)		
	External bus clock (Βφ)	: 50 MHz (12.5 MHz multiplied by 4)		
Operation voltage	3.3 V			
Operation mode				
External memory	• SDRAM (area 2) : K4S641632K-UC75			
	• SRAM (area 4)	: R1LV1616RSD-7SR		
Development tool	High-performance Embedded Work	shop (HEW) Ver.4.03.00		
C/C++ compiler	H8S, H8/300 SERIES C/C++ Compiler Ver.6.01.03 from Renesas Technology			
Compiler options	-cpu = H8SXA:24MD, -optimize = 1			
Linker options	start = PResetPRG, PIntPRG/0400, P, C\$DSEC, C\$BSEC, D/0800,			
	B, R/0FF2000, S/0FFBE00			

### Table 4 SDRAM Specifications

Item	Detail
Product name	K4S641632K-UC75 (Samsung Electronics Corp.)
Configuration	1 Mword × 16 bits × 4 banks
Capacity	64 Mbits
CAS latency	2/3 (programmable)
Refresh interval	4,096 refresh cycles per 64 ms
Row address	A11 to A0
Column address	A7 to A0
Number of banks Four banks for operation controlled by BA0 and B	

## Table 5 SRAM Specifications

Item	Detail
Product name	R1LV1616RSD-7SR (Renesas Technology Corp.)
Configuration	1 Mword × 16 bits
Capacity	16 Mbits

Note: The upper 1 Mbyte of SRAM is used for this application note (because 1 Mbyte is the maximum space in area 4).



# Table 6 SDRAM Mode Settings

Item	Setting
Operation code (OPCODE)	Burst read/single write
CAS latency (LMODE)	2
Burst type (BT)	Sequential
Burst length (BL)	1
SDRAM access address	H'400440

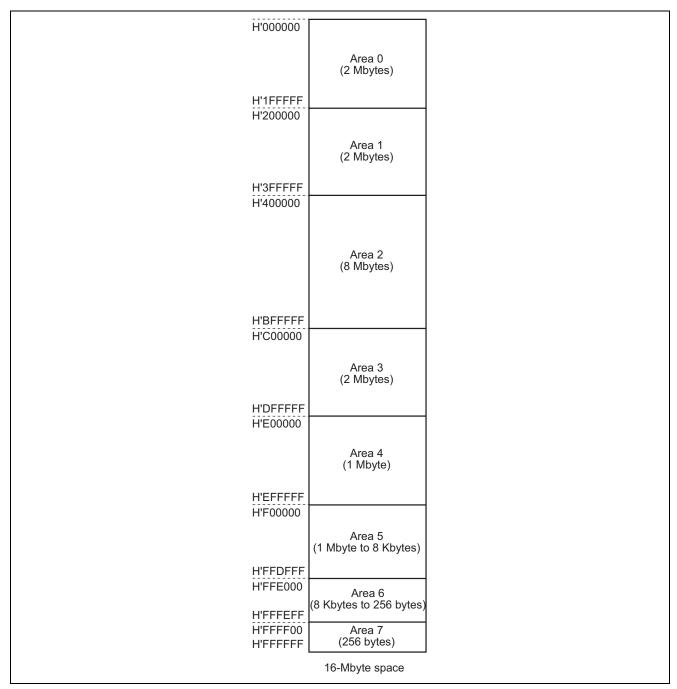


Figure 3 Address Space Area Division



## **Description of Modules Used**

#### **Normal Transfer Mode** 3.1

In normal transfer mode, data are transferred in one-data access size units in response to each transfer request. Total transfer size can be set up to 4 Gbytes in the EXDMA transfer count register (EDTCR).

Examples of timing and operation in this mode are shown in figure 4 and figure 5, respectively.

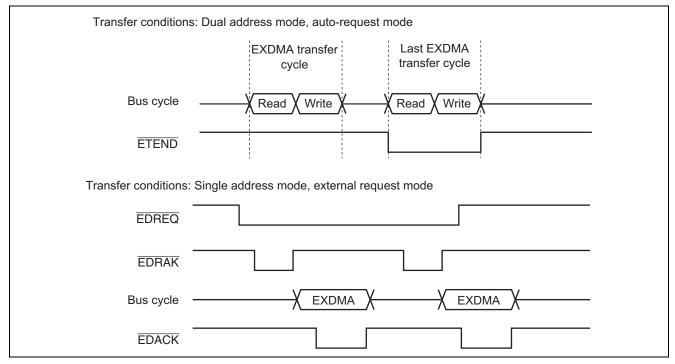


Figure 4 **Example of Timing in Normal Transfer Mode** 

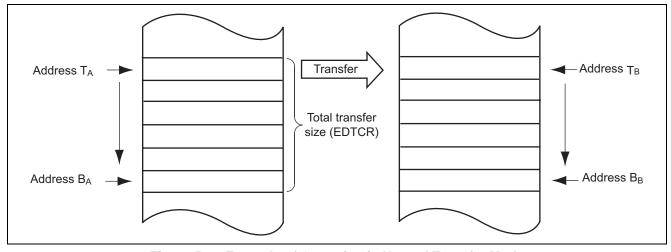


Figure 5 **Example of Operation in Normal Transfer Mode** 



#### 3.2 **Extended Repeat Area Function**

The EXDMAC has a function for designating an extended repeat area for source addresses and/or destination addresses. When an extended repeat area is designated, the address register values repeat within the range specified as the extended repeat area. Normally, when a ring buffer is involved in a transfer, an operation is required to restore the address register value to the buffer start address each time the address register value becomes the last address in the buffer (i.e. when ring buffer address overflow occurs). However, if the extended repeat area function is used, the operation that restores the address register value to the buffer start address is processed automatically within the EXDMAC.

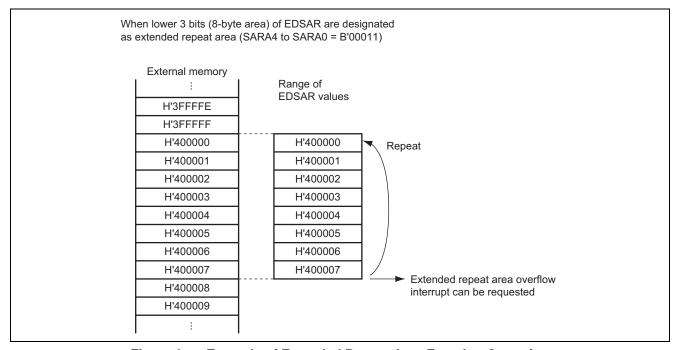


Figure 6 **Example of Extended Repeat Area Function Operation** 



# 4. Principle of Operation

Operation in this application note is shown in figure 7.

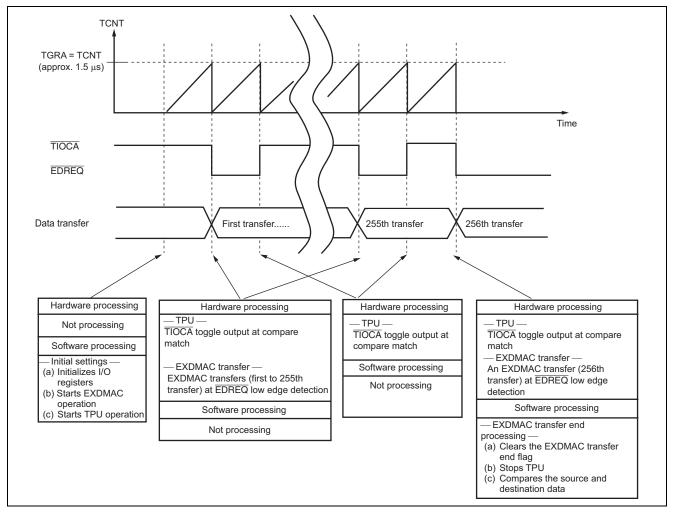


Figure 7 Operation



## 5. Description of Software

### 5.1 List of Functions

#### Table 7 List of Functions

Function Name	Description					
main	<ul> <li>Main routine         Calls functions of init and cmp_data, sets operations of EXDMAC and TPU, and judges whether an EXDMAC transfer is ended.     </li> </ul>					
init	<ul> <li>Initialization routine         Initializes registers and memory areas to be used, and sets data in the EXDMAC transfer source area.     </li> </ul>					
cmp_data	Transfer data compare routine     Compares the source and destination data					

# 5.2 Description of Functions

#### 5.2.1 main Function

1. Functional overview

The main function initializes registers and RAM by calling function init, and operates the EXDMAC and TPU. After the end of transfer by the EXDMAC, it calls function cmp\_data to compare the transfer source data with the transfer destination data.

2. Arguments

None

3. Return values

None

4. Description of internal registers used

The internal registers used in this sample task are described below. The settings shown in these tables are the values used in this sample task and differ from the initial values.

• EXDMA mode control register (EDMDR) Number of bits: 32 Address: H'FFFC94

Bit	Bit Name	Setting Value	R/W	Description
		value		Description
31	DTE	1	R/W	Data Transfer Enable
				Enables or disables data transfer on the corresponding channel.
				When this bit is set to 1, this indicates that an EXDMA operation is in operation.
				With external requests, transfer processing begins when a transfer
				request is issued after this bit has been set to 1.
				1: Data transfer enabled (during an EXDMA operation)
16	DTIF	0	R/W	Data Transfer Interrupt Flag
				Flag indicating that a transfer end interrupt request has occurred
				by the transfer counter.
				Transfer end interrupt request is not generated by the transfer counter



•	Timer start register (TST	R) Nur	nber of	bits: 8 Address: H'FFFFBC
	Bit S	Setting		
Bi	t Name \	Value	R/W	Description
0	CST0	1	R/W	Counter Start 0
				Selects operation or stoppage for TCNT.
				1: TCNT_0 performs count operation

#### 5. Flowchart

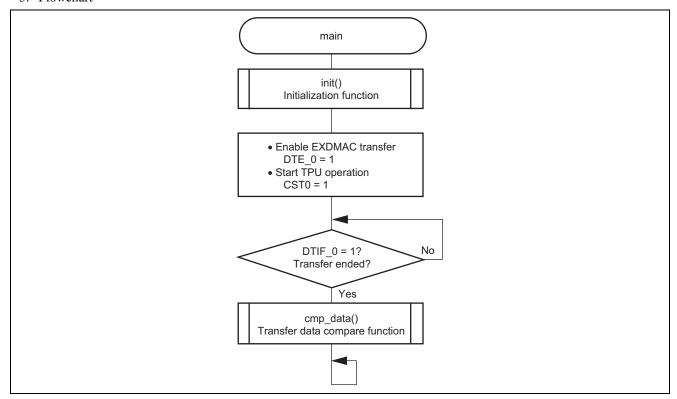


Figure 8 Flowchart (main)



#### 5.2.2 init Function

1. Functional overview

The init function initializes I/O registers and memory, and sets transfer source data.

2. Arguments

None

3. Return values

None

4. Description of internal registers used

The internal registers used in this sample task are described below. The settings shown in these tables are the values used in this sample task and differ from the initial values.

System clock control register (SCKCR) Number of bits: 16 Address: H'FFFDC4

		Setting		
Bit	Bit Name	Value	R/W	Description
10	ICK2	0	R/W	System Clock (Iφ) Select
9	ICK1	0		Select the frequency of the system clock and the clock provided
8	ICK0	0		to the CPU, EXDMÁC, DMAĆ, and DTC.
				000: Input clock × 4
6	PCK2	0	R/W	Peripheral Module Clock (Pφ) Select
5	PCK1	0		Select the frequency of the peripheral module clock.
4	PCK0	1		001: Input clock × 2
2	BCK2	0	R/W	External Bus Clock (Bø) Select
1	BCK1	0		Select the frequency of the external bus clock.
0	BCK0	0		000: Input clock × 4

MSTPCRA controls module stop mode. Setting a bit to 1 makes the corresponding module enter the stop mode, while clearing the bit to 0 makes the module exit the stop mode.

Module stop control register A (MSTPCRA) Number of bits: 16 Address: H'FFFDC8

Bit	Bit Name	Setting Value	R/W	Description
15	ACSE	0	R/W	All-Module-Clock-Stop Mode Enable Enables/disables all-module-clock-stop mode for reducing current consumption after the bus controller and I/O ports operation stop when the CPU executes the SLEEP instruction after all the on-chip peripheral modules controlled by MSTPCR has entered module stop mode  0: All-module-clock-stop mode disabled
14	MSTPA14	0	R/W	EXDMA controller (EXDMAC)
0	MSTPA0	0	R/W	16-bit timer pulse unit (TPU channels 5 to 0)

Bus width control register (ABWCR) Number of bits: 16 Address: H'FFFD84

Bit	Bit Name	Setting Value	R/W	Description
12	ABWH4	0	R/W	Area 7 to 0 Bus Width Control
10	ABWH2	0		Select whether the corresponding area is to be designated as
4	ABWL4	1		8-bit access space or 16-bit access space.
2	ABWL2	1		ABWHn ABWLn (n = 7 to 0)
				0 1: Area n is designated as 16-bit access space



• Access state control register (ASTCR) Number of bits: 16 Address: H'FFFD86

	sess state control i	Setting		Number of this 10 Madress, ITTT 200
Bit	Bit Name	Value	R/W	Description
12	AST4	1	R/W	Select whether the corresponding area is to be designated as 2-
10	AST2	1		or 3-state access space.
				1: Area n is designated as 3-state access space

• Wait control register A (WTCRA) Number of bits: 16 Address: H'FFFD88

	Bit	Setting		
Bit	Name	Value	R/W	Description
2	W42	1	R/W	Area 4 Wait Control 2 to 0
1	W41	1		Select the number of program wait cycles when accessing area
0	W40	1		4.
				111: 7 program wait cycles inserted

• Wait control register B (WTCRB) Number of bits: 16 Address: H'FFFD8A

	Bit	Setting		
Bit	Name	Value	R/W	Description
10	W22	0	R/W	Area 2 Wait Control 2 to 0
9	W21	0		Select the number of program wait cycles when accessing area
8	W20	1		2.
				When SDRAM is connected, the CAS latency is specified. At
				this time, W22 is ignored.
				01: SDRAM with a CAS latency of 2 is connected.

• Idle control register (IDLCR) Number of bits: 16 Address: H'FFFD90

		Setting		
Bit	Bit Name	Value	R/W	Description
15 to 12	IDLS2 to 0	0	R/W	Idle Cycle Insertion 3 to 0
				Insert an idle cycle between bus cycles
				0: No idle cycle is inserted

• Endian control register (ENDIANCR) Number of bits: 8 Address: H'FFFD95

		Setting		
Bit	Bit Name	Value	R/W	Description
4	LE4	0	R/W	Little Endian Select
2	LE2	0		Select the endian for the corresponding area.
				0: Big endian

• SRAM mode control register (SRAMCR) Number of bits: 16 Address: H'FFFD98

		Setting		
Bit	Bit Name	Value	R/W	Description
12	BCSEL4	1	R/W	Byte Control SRAM Interface Select
10	BCSEL2	0		Select the bus interface for the corresponding area.
				0: Basic bus interface
				1: Byte control SRAM interface



• DRAM control register (DRAMCR) Number of bits: 16 Address: H'FFFDA0

Bit Name Value R/W Description  15 DRAME 1 R/W Area 2 DRAM Interface Select Selects whether or not area 2 is specified as the	
Selects whether or not area 2 is specified as the	
·	
	e
DRAM/SDRAM interface.	
When this bit is set to 1, select the type of DRA area 2 with the DTYPE bit.	M to be used in
When this bit is set to 1, the BCSEL2 bit in SRA	AMCR should be
set to 0.	
1: DRAM/SDRAM interface	
14 DTYPE 1 R/W DRAM select	
Selects the type of DRAM to be connected to a	rea 2.
1: SDRAM is connected to area 2	
11 OEE 1 R/W OE output enable	
The $\overline{\sf OE}$ signal is output when DRAM with the E	DO page mode
is connected, whereas the CKE signal is output	when SDRAM
is connected.	
1: OE/CKE signal enabled	
7 BE 1 R/W Burst Access Enable	
Enables or disables a burst access to the DRAI	M/SDRAM. The
DRAM/SDRAM is accessed in high-speed page	e mode.
1: DRAM/SDRAM is accessed in high-speed	d page mode

• DRAM access control register (DRACCR) Number of bits: 16 Address: H'FFFDA2

		Setting		
Bit	Bit Name	Value	R/W	Description
13	TPC1	0	R/W	Precharge Cycle Control
12	TPC0	0		Select the number of RAS precharge cycles on a normal access and a refresh.
				00: One cycle
9	RCD1	0	R/W	RAS-CAS Wait Control
8	RCD0	0		Determine whether to insert wait cycles between $\overline{RAS}$ and $\overline{CAS}$ assert cycles.
				00: No wait cycle inserted

• Synchronous DRAM control register (SDCR) Number of bits: 16 Address: H'FFFDA4

		Setting		
Bit	Bit Name	Value	R/W	Description
15	MRSE	0/1	R/W	Mode Register Set Enable
				Enables the setting in the SDRAM mode register.
				0: Disables to set the SDRAM mode register
				1: Enables to set the SDRAM mode register

Note: Setting the MRSE bit in SDCR to 1 enables the SDRAM mode register setting to set the SDRAM mode. After this, write to the SDRAM space in bytes.

After write access, clear the MRSE bit to 0 to disable the SDRAM mode setting.



Refresh control register (REFCR)
 Number of bits: 16
 Address: H'FFFDA6

		Setting		
Bit	Bit Name	Value	R/W	Description
10	RTCK2	0	R/W	Refresh Counter Clock Select
9	RTCK1	1		Select a clock used to count up the refresh counter from the
8	RTCK0	0		seven internal clocks generated by dividing the on-chip peripheral module clock (P $\phi$ ). When the clock is selected, the refresh counter starts to count up. 010: Counts on P $\phi$ /8
7	RFSHE	1	R/W	Refresh Control Enables or disables refresh control. 1: Refresh control enabled

• Refresh timer counter (RTCNT) Number of bits: 8 Address: H'FFFDA8

Description: RTCNT counts up on the internal clock selected by bits RTCS2 to RTCK0 in REFCR. When the

RTCNT value matches the RTCOR value (compare match), the CMF flag in REFCR is set to 1 and RTCNT is cleared to H'00. At this time, when the RFSHE bit in REFCR is 1, a refresh cycle is

generated.

Setting Value: H'00

Refresh time constant register (RTCOR)
 Number of bits: 8 Address: H'FFFDA9

Description: RTCOR specifies intervals at which a compare match for RTCOR and RTCNT is generated.

The RTCOR value is always compared with the RTCNT value. When they match, the CMF flag in

REFCR is set to 1 and RTCNT is cleared to H'00.

Setting Value: H'30 (Refresh intervals: approx. 15.36 µs)

• Port function control register 0 (PFCR0) Number of bits: 8 Address: H'FFFBC0

		Setting		
Bit	Bit Name	Value	R/W	Description
4	CS4E	1	R/W	CS7 to CS0 Enable
2	CS2E	1		Enable/disable the corresponding CS output.
				1: Pin functions as CS output pin

• Port function control register 1 (PFCR1) Number of bits: 8 Address: H'FFFBC1

		Setting		
Bit	Bit Name	Value	R/W	Description
1	CS4SA	0	R/W	CS4 Output Pin Select
0	CS4SB	0		Select the output pin for $\overline{CS4}$ when $\overline{CS4}$ output is enabled (CS4E = 1)
				00: Specifies pin PB0 as CS4-A output

• Port function control register 2 (PFCR2) Number of bits: 8 Address: H'FFFBC2

		Setting		
Bit	Bit Name	Value	R/W	Description
6	CS2S	1	R/W	CS2 Output Pin Select
				Selects the output pin for CS2 when CS2 output is enabled
				(CS2E = 1).
				1: Specifies pin PB1 as CS2-B output



<ul> <li>Port f</li> </ul>	unction control	register 4 (H	PFCR4)	Number of bits: 8 Address: H'FFFBC4
		Setting		
Bit	Bit Name	Value	R/W	Description
7 to 0	A23E to	1	R/W	Address A23 to A16 Enable
	A16E			Enable/disable the address output (A23 to A16).
				1: Enables the A23 to A16 output

Port function control register 8 (PFCR8) Number of bits: 8 Address: H'FFFBC8

		Setting		
Bit	Bit Name	Value	R/W	Description
1	EDMAS0A	0	R/W	EXDMAC Control Pin Select
0	EDMAS0B	0		Select the I/O port to control EXDMAC_0.
				00: Specify pins P10 to P13 as EXDMAC control pin

•	Data direction register (P2DDR)	Number of bits: 8	Address: H'FFFB81
•	Data direction register (P3DDR)	Number of bits: 8	Address: H'FFFB82
•	Data direction register (PDDDR)	Number of bits: 8	Address: H'FFFB8A
•	Data direction register (PEDDR)	Number of bits: 8	Address: H'FFFB8D
•	Data direction register (PFDDR)	Number of bits: 8	Address: H'FFFB8E

Description: DDR is an 8-bit write-only register that specifies a port I/O for each bit.

Setting value:

Data register (P3DR) Number of bits: 8 Address: H'FFFF52

Description: DR is an 8-bit readable/writable register that stores output data of the pins to be used as the general

output port.

Setting value: H'FF

Input buffer control register (P1ICR) Number of bits: 8 Address: H'FFFB90

Description: ICR is an 8-bit readable/writable register that controls the port input buffers.

Setting value: H'01

Note: This value is set to H'01 to use the  $\overline{\text{EDREQ}}$  pin as the input pin.

EXDMA source address register (EDSAR) Number of bits: 32 Address: H'FFFC80

Description: EDSAR is a 32-bit readable/writable register that specifies the transfer source address. An address

update function is provided that updates the register contents to the next transfer source address

each time transfer processing is performed.

the start address of area 2. Setting value:

EXDMA destination address register (EDDAR) Number of bits: 32 Address: H'FFFC84

Description: EDDAR is a 32-bit readable/writable register that specifies the transfer destination address. An

address update function is provided that updates the register contents to the next transfer destination

address each time transfer processing is performed.

the start address of area 4 Setting value:

# Transfer between Synchronous DRAM and External SRAM with EXDMAC (Extended Repeat Area Function)

EXDMA transfer count register (EDTCR) Number of bits: 32 Address: H'FFFC8C

EDTCR is a 32-bit readable/writable register that specifies the size of data to be transferred (total Description:

transfer size). The value according to the data access size is decremented every data transfer.

Setting value: H'100

EXDMA mode control register (EDMDR) Number of bits: 32 Address: H'FFFC94

	<b>-</b>	Setting		<b>-</b>
Bit	Bit Name	Value	R/W	Description
31	DTE	0	R/W	Data Transfer Enable
				Enables or disables data transfer on the corresponding
				channel.
				0: Data transfer disabled
27	EDREQS	1	R/W	EDREQ select
				Selects whether low level or falling edge detection of the
				EDREQ signal is used in external request mode.
				1: Falling edge detection
				(the first transfer is detected on a low level after a
				transfer is enabled.)
15	DTSZ1	0	R/W	Data Access Size 1 and 0
14	DTSZ0	0		Select the data access size for a transfer.
				00: Byte-size (8 bits)
13	MDS1	0	R/W	Transfer Mode Select 1 and 0
12	MDS0	0		Select the transfer mode.
				00: Normal transfer mode
8	DTIE	0	R/W	Data Transfer Interrupt Enable
				Enables or disables a transfer end interrupt request by the
				transfer counter.
				0: Transfer end interrupt request disabled
7	DTF1	1	R/W	Data Transfer Factor 1 and 0
6	DTF0	1		Select a source to activate EXDMAC.
				11: External request
2	EDMAP2	1	R/W	EXDMA Priority Levels 2 to 0
1	EDMAP1	1		Select the EXDMAC priority level to determine the priority over
0	EDMAP0	1		CPU.
				111: Priority level 7 (highest)

source address are specified as the extended repeat



EXDMA address control register (EDACR) Number of bits: 32 Address: H'FFFC98 Setting **Description Bit Name** R/W Bit Value 31 **AMS** 0 R/W Address Mode Select Selects single address mode or dual address mode. 0: Dual address mode 21 SAT1 1 R/W Source Address Update Mode 1 and 0 20 SAT0 0 Specify incrementing/decrementing of the transfer source address (EDSAR). 10: Incremented 17 DAT1 1 R/W Destination Address Update Mode 1 and 0 Specify incrementing/decrementing of the transfer destination 16 DAT0 0 address (EDDAR). 10: Incremented 12 SARA4 R/W Source Address Extended Repeat Area 0 11 SARA3 0 Specify the extended repeat area on the transfer source address register (EDSAR). With the extended repeat area, the 10 SARA2 0 specified lower address bits are updated and the remaining 9 SARA1 1 upper address bits are fixed. SARA0 8 1 00011: The three lower-order bits (for 8 bytes) of transfer

• Timer control register (TCR) Number of bits: 8 Address: H'FFFFC0

		Setting		
Bit	Bit Name	Value	R/W	Description
7	CCLR2	0	R/W	Counter Clear 2 to 0
6	CCLR1	0		Select the TCNT counter clearing source.
5	CCLR0	1		001: TCNT cleared by TGRA compare match/input capture
4	CKEG1	0	R/W	Clock Edge 1 and 0
3	CKEG0	0		Select the input clock edge.
				00: Counted at an internal clock falling edge
2	TPSC2	0	R/W	Timer Prescaler 2 to 0
1	TPSC1	0		Select the TCNT counter clock.
0	TPSC0	0		000: Counts on internal clock Pφ/1

area.

• Timer I/O control register \_H (TIOR\_H) Number of bits: 8 Address: H'FFFFC2

		Setting		
Bit	Bit Name	Value	R/W	Description
3	IOA3	0	R/W	I/O Control A3 to A0
2	IOA2	1		Specify the function of TGRA.
1	IOA1	1		0111 TIOCA0 pin initial value is 1. Toggle output at compare
0	IOA0	1		match.



• Time	er interrupt enable	e register ('	ΓIER)	Number of bits: 8	Address: H'FFFFC4
		Setting			
Bit	Bit Name	Value	R/W	Description	
0	TGIEA	0	R/W	TGR Interrupt	Enable A
				Enables/disab	les interrupt requests (TGIA) by the TGFA bit
				when the TGF	A bit in TSR is set to 1.
				0: Interrupt re	quests (TGIA) by TGFA bit disabled

• Timer counter (TCNT) Number of bits: 16 Address: H'FFFFC6

Description: TCNT is a 16-bit readable/writable counter.

TCNT is initialized to H'0000 by a reset or in hardware standby mode.

Setting Value: H'0000

• Timer general register (TGR) Number of bits: 16 Address: H'FFFFC8

Description: TGR is a 16-bit readable/writable register for use in output compare and input capture.

Setting Value: H'0025 (TPU period: approx. 1.5 µs)

Timer start register (TSTR) Number of bits: 8 Address: H'FFFFBC

Bit	Bit Name	Setting Value	R/W	Description
0	CST0	0	R/W	Counter Start 0
				Selects operation or stoppage for TCNT.
				0: TCNT_0 count operation is stopped

#### 5. Flowchart

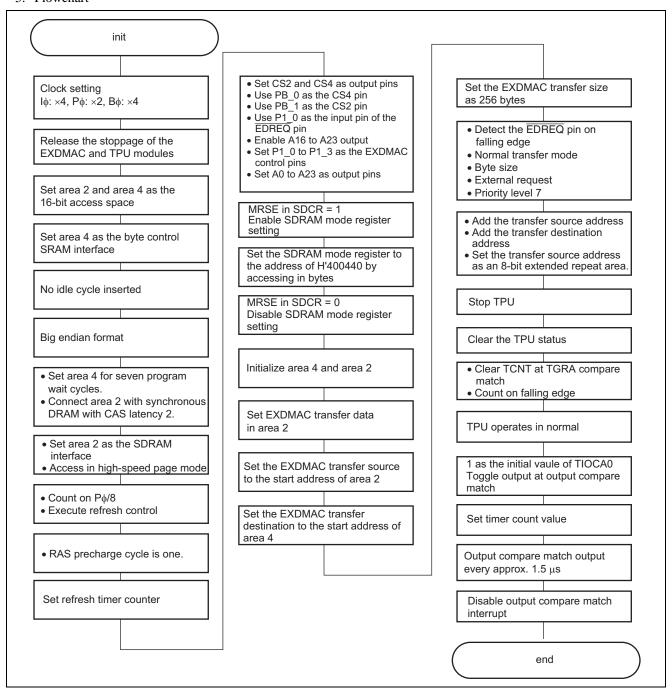


Figure 9 Flowchart (init)

(Extended Repeat Area Function)

#### 5.2.3 cmp\_data Function

1. Functional overview

The cmp\_data function compares the transfer source data with the transfer destination data and outputs the result to

2. Arguments

None

3. Return values

None

4. Description of internal registers used

The internal registers used in this sample task are described below. The settings shown in these tables are the values used in this sample task and differ from the initial values.

EXDMA mode control register (EDMDR) Number of bits: 32 Address: H' 'FFFC94

	Bit	Setting		
Bit	Name	Value	R/W	Description
16	DTIF	0	R/W	Data Transfer Interrupt Flag
				Flag indicating that a transfer end interrupt request has occurred by the transfer counter.
				<ol> <li>Transfer end interrupt request is not generated by the transfer counter</li> </ol>

Timer start register (TSTR) Number of bits: 8 Address: H'FFFFBC

Bit	Bit Name	Setting Value	R/W	Description
0	CST0	0	R/W	Counter Start 0
				Selects operation or stoppage for TCNT.
				0: TCNT_0 count operation is stopped

Data Register (P3DR) Number of bits: 8 Address: H'FFFF52

Description: DR is an 8-bit readable/writable register that stores output data of the pins to be used as the general

output port.

Setting Value: H'55, H'FF

#### 5. Flowchart

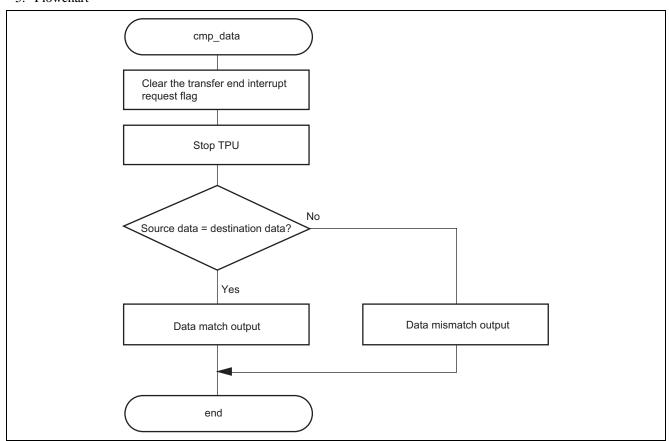


Figure 10 Flowchart (cmp\_data)



### **Precautions**

- 1. When pins of the device are used as the input pins of peripheral module, the corresponding bit in the input buffer control register (PnICR) is set to 1.
  - For details, refer to the following appropriate hardware manual.
- 2. Interrupt requests from the on-chip peripheral modules cannot be used as the sources of EXDMAC activation. For details, refer to the following appropriate hardware manual.

#### 7. **Documents for Reference**

- Hardware Manual
  - H8SX/1668R Group Hardware Manual

The most up-to-date version of this document is available on the Renesas Technology Website.

- Technical News and Technical Updates The most up-to-date information is available on the Renesas Technology Website.
- **H8SX Family Application Note**

Synchronous DRAM Interface: document No. REJ06B0659-0200

The most up-to-date version of this document is available on the Renesas Technology Website.



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Rev.	Date	Page	Summary	
1.00	May.20.08	_	First edition issued	



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